



30V P-Channel Enhancement Mode MOSFET

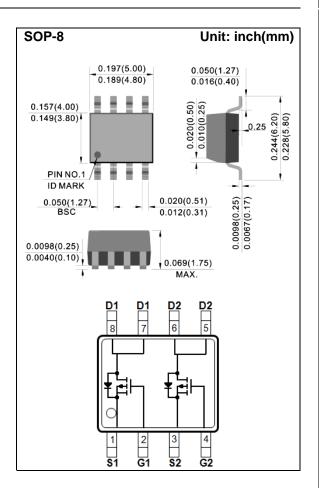
Voltage -30 V Current -5A

Features

- RDS(ON) , VGS@-10V, ID@-5.0A<54mΩ
- RDS(ON), VGS@-4.5V, ID@-3.5A<61mΩ
- RDS(ON), VGS@-2.5V, ID@-2.5A<82mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOP-8 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9801



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	5	Α
Pulsed Drain Current		I _{DM}	20	Α
Power Dissipation	T _a =25°C	P_{D}	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ hetaJA}$	62.5	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS			
Static									
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-30	-	-	V			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-0.5	-0.97	-1.3	V			
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-5.0A	-	45	54	mΩ			
		V _{GS} =-4.5V,I _D =-3.5A	-	51	61				
		V _{GS} =-2.5V,I _D =-2.5A	-	67	82				
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-0.01	-1.0	uA			
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 12V,V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA			
Dynamic ^(Note 5)	Dynamic ^(Note 5)								
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-5.0A, V _{GS} =4.5V (Note 1,2)	-	9.1	-	nC			
Gate-Source Charge	Q_gs		-	1.8	-				
Gate-Drain Charge	Q_gd		-	2.6	-				
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	816	-	pF			
Output Capacitance	Coss		-	64	-				
Reverse Transfer Capacitance	Crss		-	42	-				
Turn-On Delay Time	td _(on)	V_{DD} =-15V, I_{D} =-5.0A, V_{GS} =-10V, R_{G} =6 Ω (Note 1,2)	-	5	-				
Turn-On Rise Time	tr		-	45	-	ns			
Turn-Off Delay Time	td _(off)		-	66	-				
Turn-Off Fall Time	tf		-	10	-				
Drain-Source Diode									
Maximum Continuous Drain-Source		I _S	_	_	-2	А			
Diode Forward Current	IS		_	_	-2				
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	0.77	-1.2	V			

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. R@JA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
- 5. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

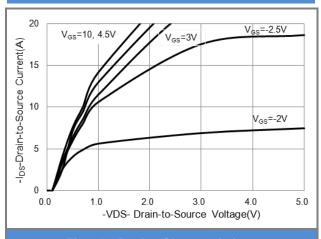


Fig.1 On-Region Characteristics

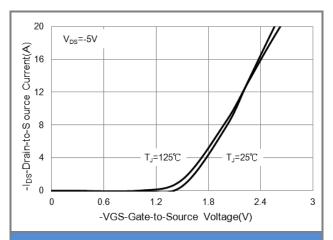


Fig.2 Transfer Characteristics

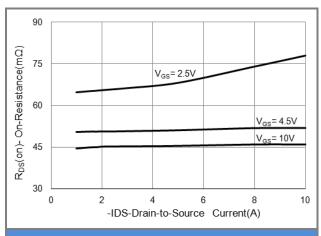


Fig.3 On-Resistance vs. Drain Current

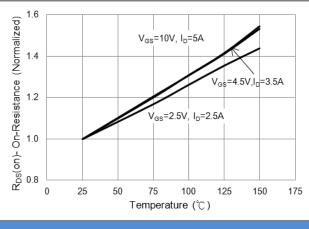


Fig.4 On-Resistance vs. Junction temperature

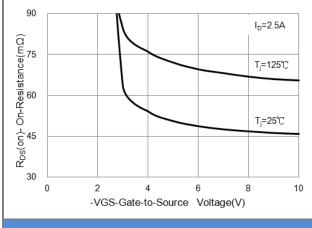


Fig.5 On-Resistance Variation with VGS.

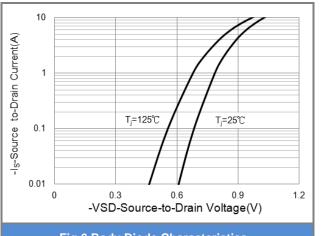


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

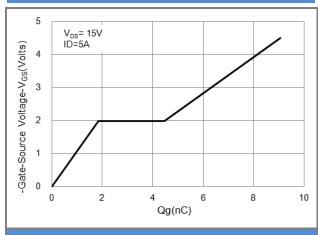


Fig.7 Gate-Charge Characteristics

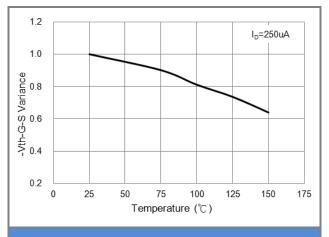


Fig.8 Threshold Voltage Variation with Temperature.

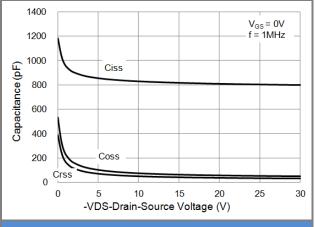


Fig.9 Capacitance vs. Drain-Source Voltage.

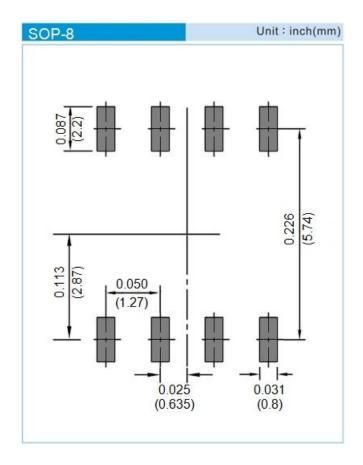




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9801_R2_00001	SOP-8	2.5K pcs / 13" reel	L9801	Halogen free

MOUNTING PAD LAYOUT







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